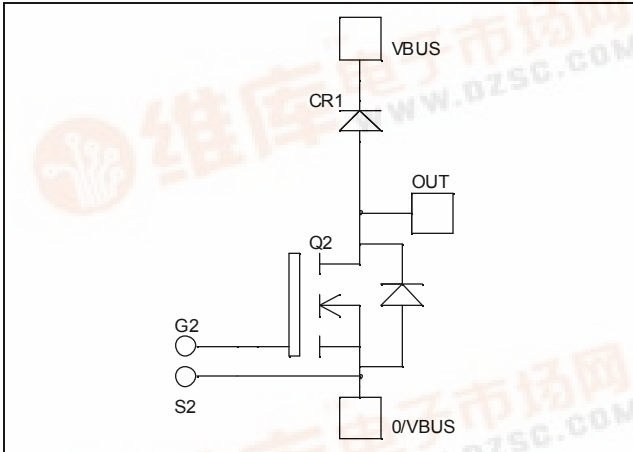




APT50DAM17G

Boost chopper MOSFET Power Module

$V_{DSS} = 500V$
 $R_{DSon} = 17m\Omega \text{ typ @ } T_j = 25^\circ C$
 $I_D = 180A \text{ @ } T_c = 25^\circ C$



Application

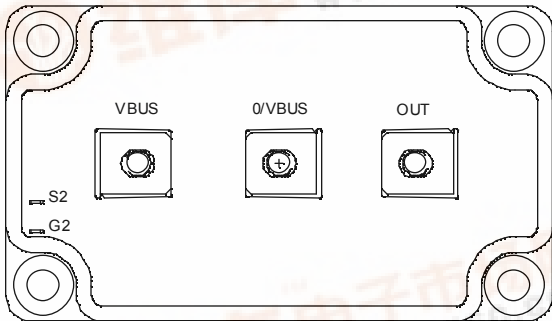
- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



Absolute maximum ratings

| Symbol | Parameter | Max ratings | Unit |
|------------|---|--------------------|------------|
| V_{DSS} | Drain - Source Breakdown Voltage | 500 | V |
| I_D | Continuous Drain Current | $T_c = 25^\circ C$ | 180 |
| | | $T_c = 80^\circ C$ | 135 |
| I_{DM} | Pulsed Drain current | 720 | A |
| V_{GS} | Gate - Source Voltage | ± 30 | V |
| R_{DSon} | Drain - Source ON Resistance | 20 | m Ω |
| P_D | Maximum Power Dissipation | $T_c = 25^\circ C$ | 1250 |
| I_{AR} | Avalanche current (repetitive and non repetitive) | 51 | A |
| E_{AR} | Repetitive Avalanche Energy | 50 | mJ |
| E_{AS} | Single Pulse Avalanche Energy | 3000 | |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit | |
|--------------|---------------------------------|--------------------------------------|---------------------------|-----|-----------|------------------|---------------|
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{GS} = 0V, V_{DS} = 500V$ | $T_j = 25^\circ\text{C}$ | | | 400 | μA |
| | | $V_{GS} = 0V, V_{DS} = 400V$ | $T_j = 125^\circ\text{C}$ | | | 2000 | |
| $R_{DS(on)}$ | Drain – Source on Resistance | $V_{GS} = 10V, I_D = 90A$ | | 17 | 20 | $\text{m}\Omega$ | |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{GS} = V_{DS}, I_D = 10\text{mA}$ | 3 | | 5 | V | |
| I_{GSS} | Gate – Source Leakage Current | $V_{GS} = \pm 30V, V_{DS} = 0V$ | | | ± 200 | nA | |

Dynamic Characteristics

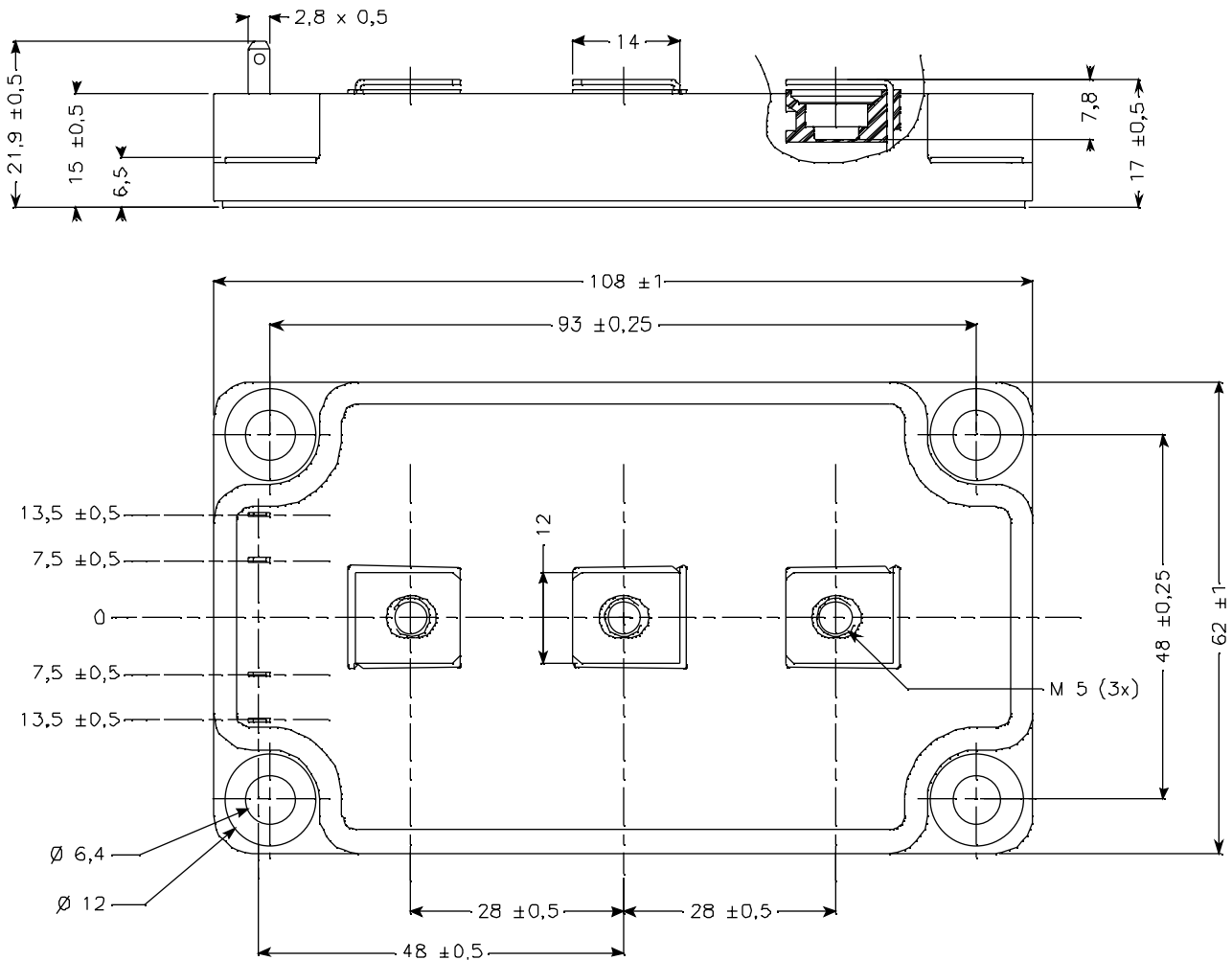
| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|--------------|------------------------------|---|-----|------|-----|---------------|
| C_{iss} | Input Capacitance | $V_{GS} = 0V$ | | 28 | | nF |
| C_{oss} | Output Capacitance | $V_{DS} = 25V$ | | 5.6 | | |
| C_{rss} | Reverse Transfer Capacitance | $f = 1\text{MHz}$ | | 0.36 | | |
| Q_g | Total gate Charge | $V_{GS} = 10V$ | | 560 | | nC |
| Q_{gs} | Gate – Source Charge | $V_{Bus} = 250V$ | | 160 | | |
| Q_{gd} | Gate – Drain Charge | $I_D = 180A$ | | 280 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 333V$ $I_D = 180A$ $R_G = 0.5\Omega$ | | 21 | | ns |
| T_r | Rise Time | | | 38 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | 75 | | |
| T_f | Fall Time | | | 93 | | |
| E_{on} | Turn-on Switching Energy | Inductive switching @ 25°C $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 180A, R_G = 0.5\Omega$ | | 4140 | | μJ |
| E_{off} | Turn-off Switching Energy | | | 3380 | | |
| E_{on} | Turn-on Switching Energy | Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 333V$ $I_D = 180A, R_G = 0.5\Omega$ | | 6224 | | μJ |
| E_{off} | Turn-off Switching Energy | | | 4052 | | |

Chopper diode ratings and characteristics

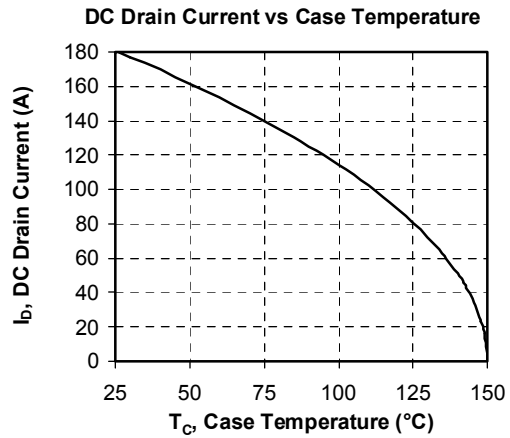
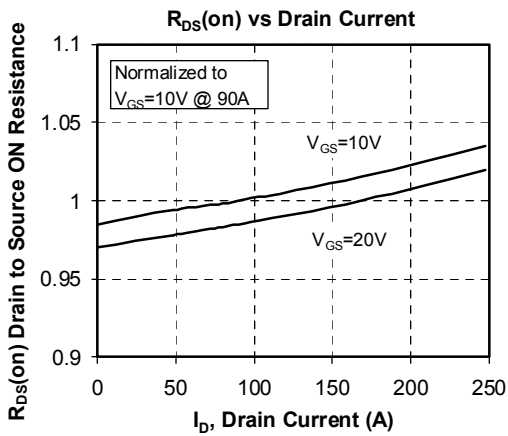
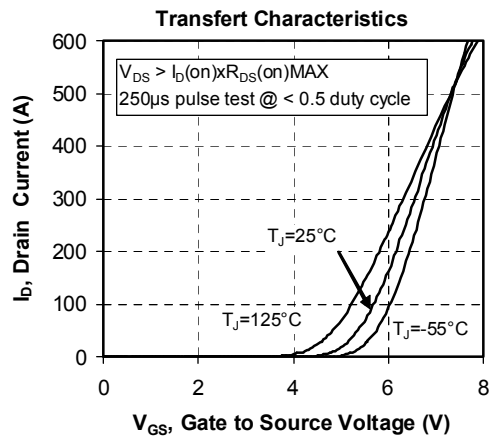
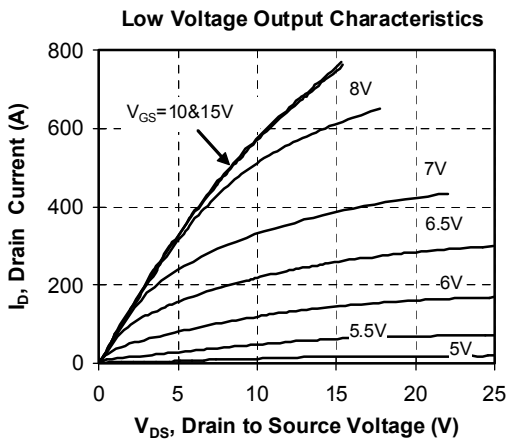
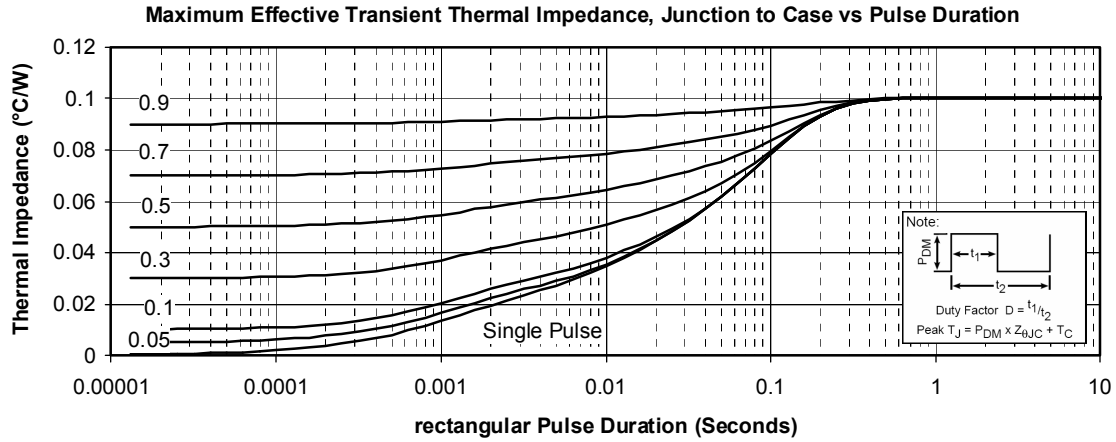
| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit | |
|-----------|---|--|---------------------------|------|-----|------|---------------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | 600 | | | V | |
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 600V$ | $T_j = 25^\circ\text{C}$ | | | 500 | μA |
| | | | $T_j = 125^\circ\text{C}$ | | | 1000 | |
| I_F | DC Forward Current | | | 180 | | A | |
| V_F | Diode Forward Voltage | $I_F = 180A$ | | 1.6 | 1.8 | V | |
| | | $I_F = 360A$ | | 1.9 | | | |
| | | $I_F = 180A$ | $T_j = 125^\circ\text{C}$ | 1.4 | | | |
| t_{rr} | Reverse Recovery Time | $I_F = 180A$ $V_R = 400V$ $di/dt = 600A/\mu\text{s}$ | $T_j = 25^\circ\text{C}$ | 130 | | ns | |
| | | | $T_j = 125^\circ\text{C}$ | 170 | | | |
| Q_{rr} | Reverse Recovery Charge | $I_F = 180A$ $V_R = 400V$ $di/dt = 600A/\mu\text{s}$ | $T_j = 25^\circ\text{C}$ | 660 | | nC | |
| | | | $T_j = 125^\circ\text{C}$ | 2760 | | | |

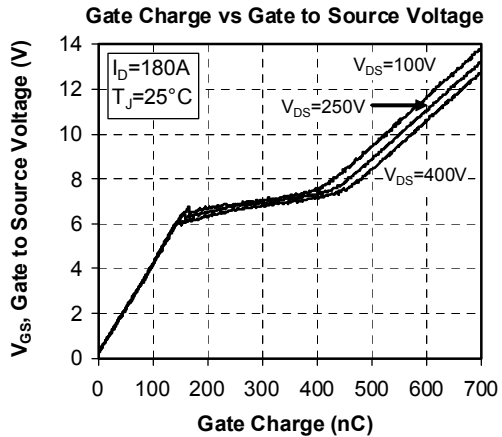
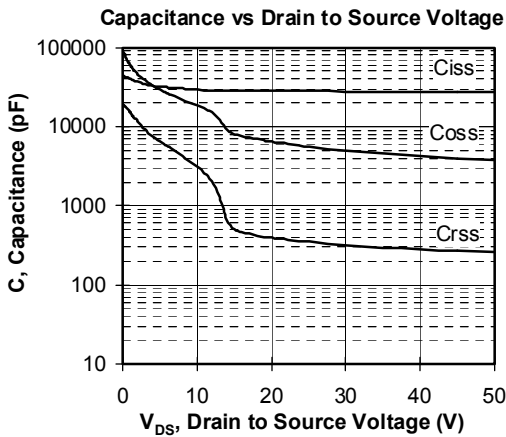
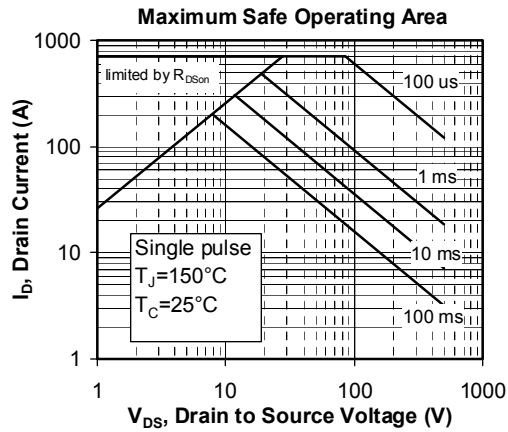
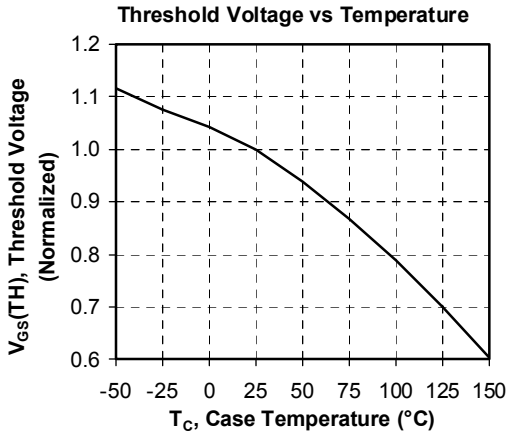
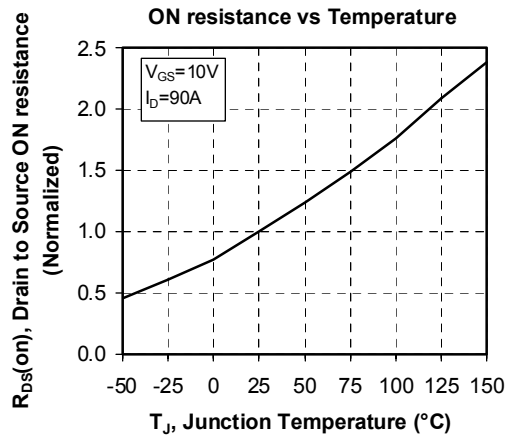
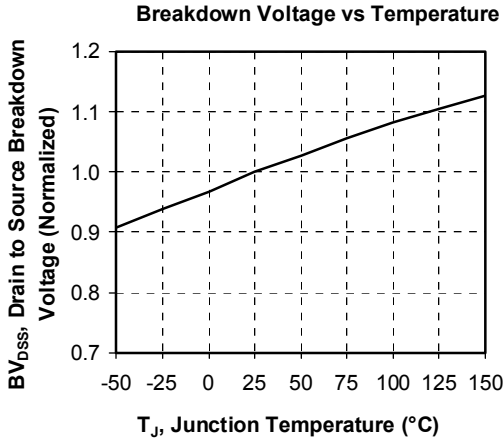
Thermal and package characteristics
Symbol Characteristic
Min Typ Max Unit

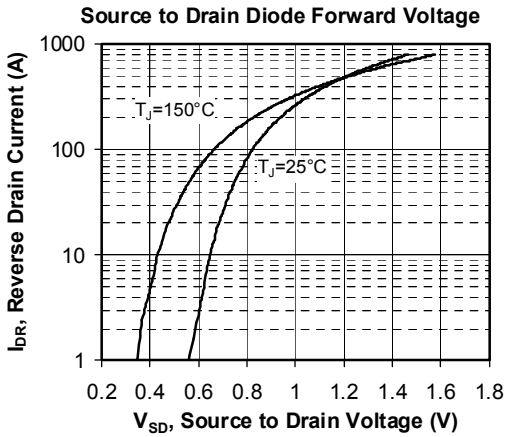
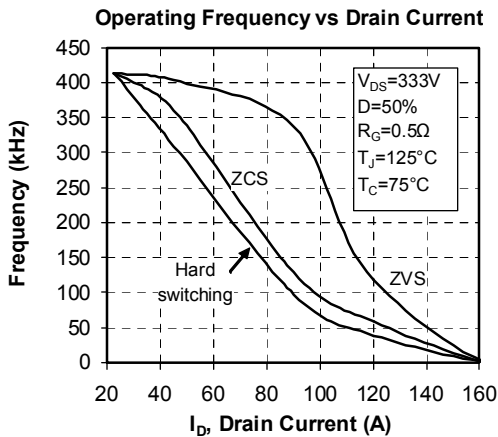
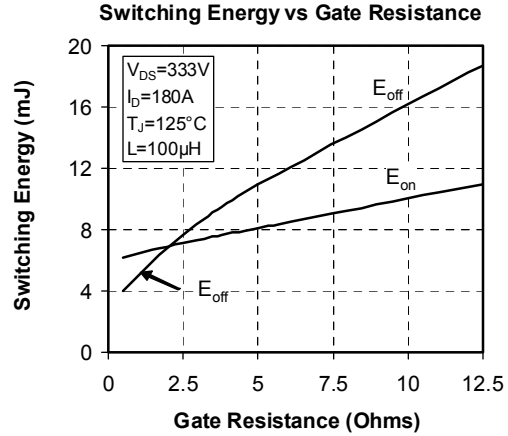
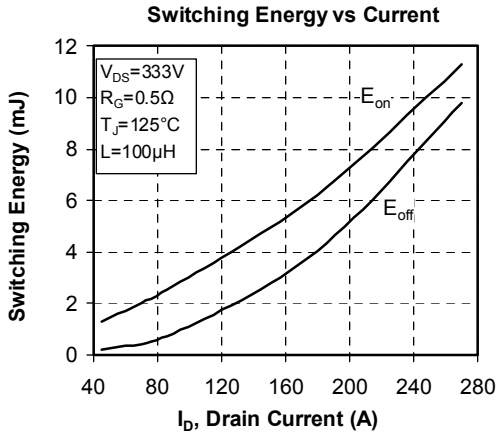
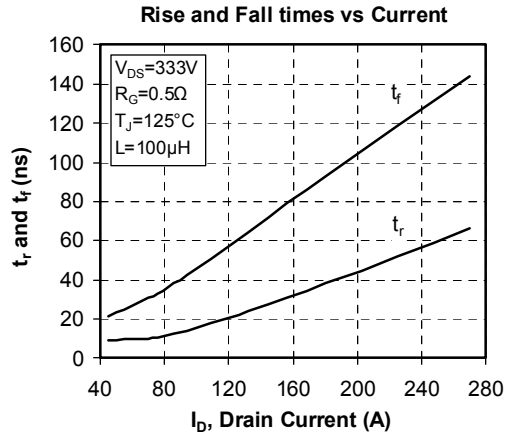
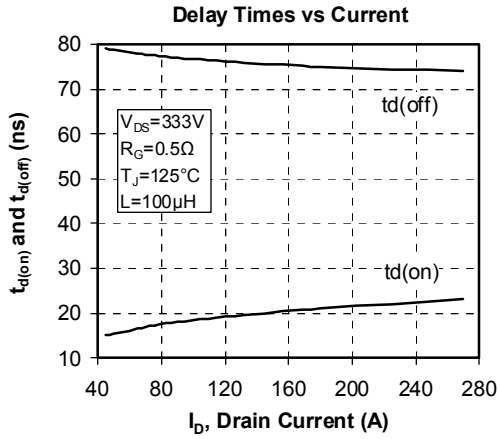
| Symbol | Characteristic | Min Typ Max Unit | | | | |
|------------|---|------------------|-------------------------------------|------------|-----|-----|
| | | R_{thJC} | Junction to Case Thermal Resistance | Transistor | | 0.1 |
| | | Diode | | 0.32 | | |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case $t=1$ min, $I_{isol}<1$ mA, 50/60Hz | 2500 | | | V | |
| T_J | Operating junction temperature range | -40 | | 150 | °C | |
| T_{STG} | Storage Temperature Range | -40 | | 125 | | |
| T_C | Operating Case Temperature | -40 | | 100 | | |
| Torque | Mounting torque | To heatsink | M6 | 3 | 5 | N.m |
| | | For terminals | M5 | 2 | 3.5 | |
| Wt | Package Weight | | | 280 | g | |

SP6 Package outline (dimensions in mm)

 See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve







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